# 2SC3851/3851A

Silicon NPN Epitaxial Planar Transistor (Complement to type 2SA1488/A)

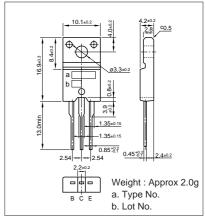
Application: Audio and PPC High Voltage Power Supply, and General Purpose

## ■ Absolute maximum ratings (Ta=25°C) ■ Electrical Characteristics

Completed	0000054	00000544	
Symbol	mbol 2SC3851 2SC3851		Unit
Vсво	80	80 100	
VCEO	60	80	V
VEBO	(	V	
Ic		Α	
lв		Α	
Pc	25(Tc:	W	
Tj	1!	°C	
Tstg	–55 tc	°C	

Electrical Characteristics (Ta=25°C)							
Symbol	Conditions		2SC3851	2SC3851A	Unit		
Сво			100	max	μΑ		
СВО		Vcb=	80	100	V		
EBO	VEB=6V		100	μΑ			
V(BR)CEO	Ic=25mA		60min	80min	V		
NFE	Vce=4V, Ic=1A		40 to				
VcE(sat)	Ic=2A, IB=0.2A		0.5max		V		
T	Vce=12V, Ie=-0.2A		15typ		MHz		
Сов	VcB=10V, f=1MHz		60typ		pF		

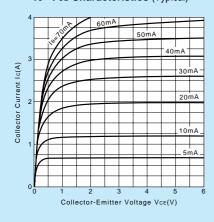
# External Dimensions FM20(TO220F)



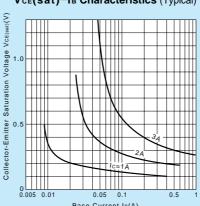
## Typical Switching Characteristics (Common Emitter)

			•		,				
Vcc (V)	R <sub>L</sub> (Ω)	Ic (A)	V <sub>BB1</sub> (V)	VBB2 (V)	I <sub>B1</sub> (mA)	I <sub>B2</sub> (mA)	ton (µs)	tstg (µs)	tf (µs)
12	6	2	10	-5	200	-200	0.2typ	1typ	0.3typ

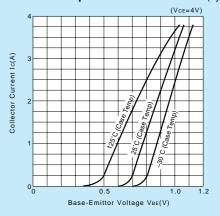
# Ic-VcE Characteristics (Typical)



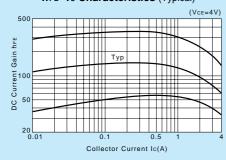
VcE(sat)-IB Characteristics (Typical)



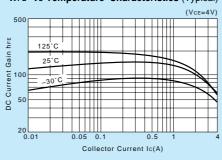
Ic-VBE Temperature Characteristics (Typical)



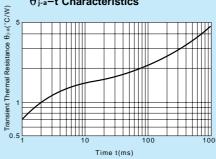
hfe-Ic Characteristics (Typical)



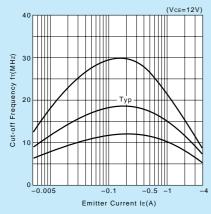
hfe-Ic Temperature Characteristics (Typical)



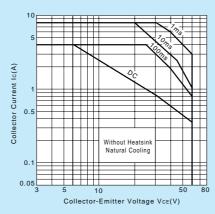
 $\theta_{j-a}$ -t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

